NSN 5962-01-373-0565

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view Online at https://aerobasegroup.com/nsn/5962-01-575-0565
Body Length:
2.096 inches
Body Width:
Between 0.510 inches and 0.620 inches
Body Height:
0.210 inches
Maximum Power Dissipation Rating:
750.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
W/clock and w/enable and 3-state output and asynchronous and w/disable and bidirectional and ultraviolet erasable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
37 input
Case Outline Source And Designator:
D-5 mil-m-38510
Current Rating Per Characteristic:
100.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
900 gate epid
Voltage Rating And Type Per Characteristic:
-2.0 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
20.00 input picofarads and 20.00 output picofarads
Memory Device Type:
Pal
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
40 printed circuit
Shelf Life:

N/a

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Demilitarization:

Yes - demil/mli

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